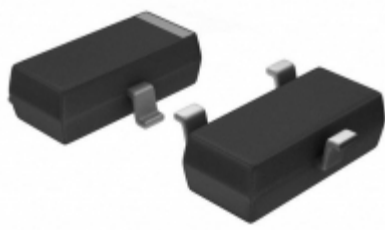






	<h2>FJV4111RMTF</h2>	
	Hersteller-Teilenummer:	FJV4111RMTF
	Hersteller / Marke:	Fairchild/ON Semiconductor
	Teil der Beschreibung:	TRANS PREBIAS PNP 200MW SOT23-3
	Datenblätter:	1.FJV4111RMTF.pdf 2.FJV4111RMTF.pdf
	RoHs Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 107850 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FJV4111RMTF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	TRANS PREBIAS PNP 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	107850 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	40V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	100 @ 1mA, 5V
Frequenz - Übergang	200MHz
Widerstand - Base (R1) (Ohm)	22k
Widerstand - Emitter-Basis (R2) (Ohm)	-
Verpackung	Tape & Reel (TR)

FJV4111RMTF ist neu im Original, Suche FJV4111RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV4111RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV4111RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV4112RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4109RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4113RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4109RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>
 <p>FJV4110RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4110RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4108RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4111RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>

heiße Teile

Mehr

⚙ FJV3108RMTF	➔ FJV3108RMTF	➔ FJV3109R	D FJV3109RMTF	➔ FJV3109RMTF
⊣ FJV3110RMTF	⚙ FJV3110RMTF	D FJV3111RMTF	➔ FJV3111RMTF	➔ FJV3112RMTF
⚙ FJV3112RMTF	⊣ FJV3113RMTF	⚙ FJV3113RMTF	➔ FJV3114RMTF	➔ FJV3114RMTF
D FJV3115RMTF	⚙ FJV3115RMTF	⊣ FJV4101RMTF	⚙ FJV4101RMTF	➔ FJV4102RLIMTF
➔ FJV4102RMTF	➔ FJV4102RMTF	⚙ FJV4103RMTF	⊣ FJV4103RMTF	➔ FJV4104RMTF
➔ FJV4104RMTF	➔ FJV4105RMTF	D FJV4105RMTF	⚙ FJV4106RMTF	⊣ FJV4106RMTF
⚙ FJV4107RMTF	D FJV4107RMTF	➔ FJV4108RMTF	➔ FJV4108RMTF	➔ FJV4109RMTF
⊣ FJV4109RMTF	⚙ FJV4110RMTF	➔ FJV4110RMTF	➔ FJV4111RMTF	➔ FJV4112RMTF
⚙ FJV4112RMTF	⊣ FJV4113RMTF	⚙ FJV4113RMTF	D FJV4114RMTF	➔ FJV4114RMTF
➔ FJV42MTF	⚙ FJV42MTF	⊣ FJV992EMTF	⚙ FJV992PMTF	➔ FJV992PMTF

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